NSN 5961-01-364-1128

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-364-1128 **Inclosure Material:** Metal **Overall Length:** 0.800 inches **Terminal Length:** 0.600 inches **Overall Width:** 0.437 inches **End Application:** E/ifscmir sensor assembly **Mounting Facility Quantity: Mounting Method:** Threaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 500.0 reverse voltage, peak and 500.0 reverse voltage, instantaneous and 350.0 reverse voltage, total rms **Current Rating Per Characteristic:** 15.00 amperes forward current, total rms megahertz and 60.00 amperes source cutoff current outside diameter **Power Rating Per Characteristic:** 41.0 watts small-signal output power, common-base preset **Capacitance Rating In Picofarads:** 150.0 **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 175.0 degrees celsius case **Terminal Type And Quantity:** 1 unthreaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:**